



# TR 907F-530-26

## Medium Frequency Thyristor

### Properties

- Amplifying gate
- High operational capability
- Optimized turn-on and turn-off parameters
- High operating frequency

### Applications

- Power switching applications

### Key Parameters

$V_{DRM}$ , $V_{RRM}$	= 2 600	V
$I_{TAV}$	= 517	A
$I_{TSM}$	= 7.0	kA
$V_{TO}$	= 2.551	V
$r_T$	= 0.430	mΩ
$t_q$	= 25.0	μs

### Types

	$V_{RRM}$ , $V_{DRM}$
TR 907F-530-26	2 600 V
TR 907F-530-24	2 400 V
TR 907F-530-22	2 200 V

Conditions:  $T_j = -40 \div 125^\circ\text{C}$ , half sine waveform,  $f = 50 \text{ Hz}$ , note 1

### Mechanical Data

$F_m$	Mounting force	$10 \pm 2 \text{ kN}$
$m$	Weight	0.26 kg
$D_s$	Surface creepage distance	25 mm
$D_a$	Air strike distance	14 mm

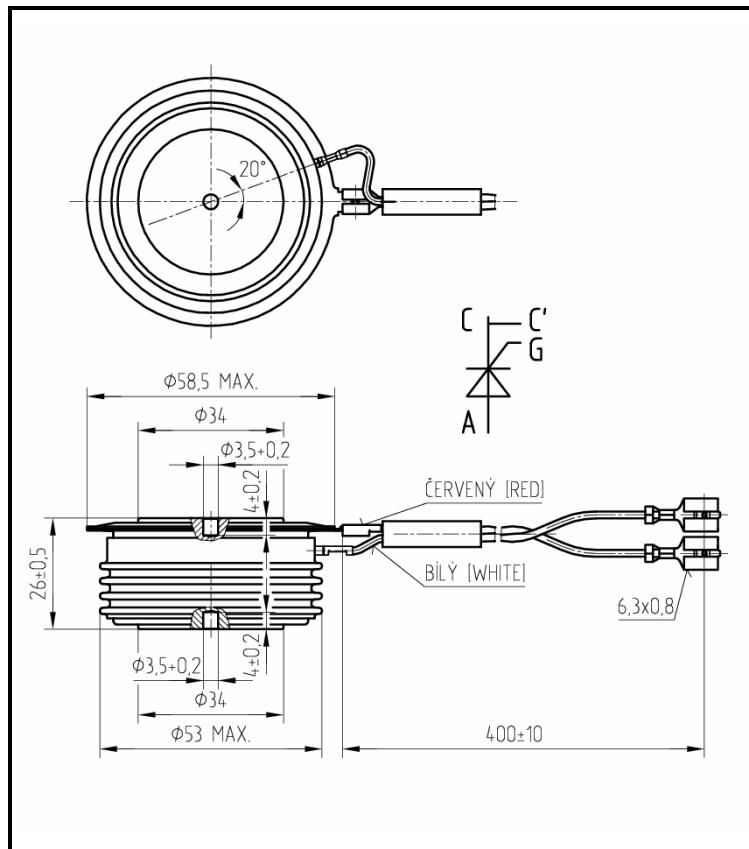


Fig. 1 Case

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<b>Maximum Ratings</b>			<b>Maximum Limits</b>	<b>Unit</b>
$V_{RRM}$	<b>Repetitive peak reverse and off-state voltage</b>	TR 907F-530-26	2 600	V
$V_{DRM}$		TR 907F-530-24	2 400	
	$T_j = -40 \div 125^\circ\text{C}$ , note 1	TR 907F-530-22	2 200	
$I_{TRMS}$	<b>RMS on-state current</b> $T_c = 70^\circ\text{C}$ , half sine waveform, $f = 50\text{ Hz}$		812	A
$I_{TAVm}$	<b>Average on-state current</b> $T_c = 70^\circ\text{C}$ , half sine waveform, $f = 50\text{ Hz}$		517	A
$I_{TSM}$	<b>Peak non-repetitive surge</b> half sine pulse, $V_R = 0\text{ V}$	$t_p = 10\text{ ms}$ $t_p = 8.3\text{ ms}$	7 000 7 480	A
$\int t$	<b>Limiting load integral</b> half sine pulse, $V_R = 0\text{ V}$	$t_p = 10\text{ ms}$ $t_p = 8.3\text{ ms}$	245 000 232 000	$\text{A}^2\text{s}$
$(di_T/dt)_{cr}$	<b>Critical rate of rise of on-state current</b> $I_T = I_{TAVm}$ , half sine waveform, $f = 50\text{ Hz}$ , $V_D = 2/3 V_{DRM}$ , $t_r = 0.3\text{ }\mu\text{s}$ , $I_{GT} = 2\text{ A}$		800	$\text{A}/\mu\text{s}$
$(dv_D/dt)_{cr}$	<b>Critical rate of rise of off-state voltage</b> $V_D = 2/3 V_{DRM}$		1 000	$\text{V}/\mu\text{s}$
$P_{GAVm}$	<b>Maximum average gate power losses</b>		3	W
$I_{FGM}$	<b>Peak gate current</b>		10	A
$V_{FGM}$	<b>Peak gate voltage</b>		12	V
$V_{RGM}$	<b>Reverse peak gate voltage</b>		10	V
$T_{jmin} - T_{jmax}$	<b>Operating temperature range</b>		-40 $\div$ 125	$^\circ\text{C}$
$T_{stgmin} - T_{stgmax}$	<b>Storage temperature range</b>		-40 $\div$ 125	$^\circ\text{C}$

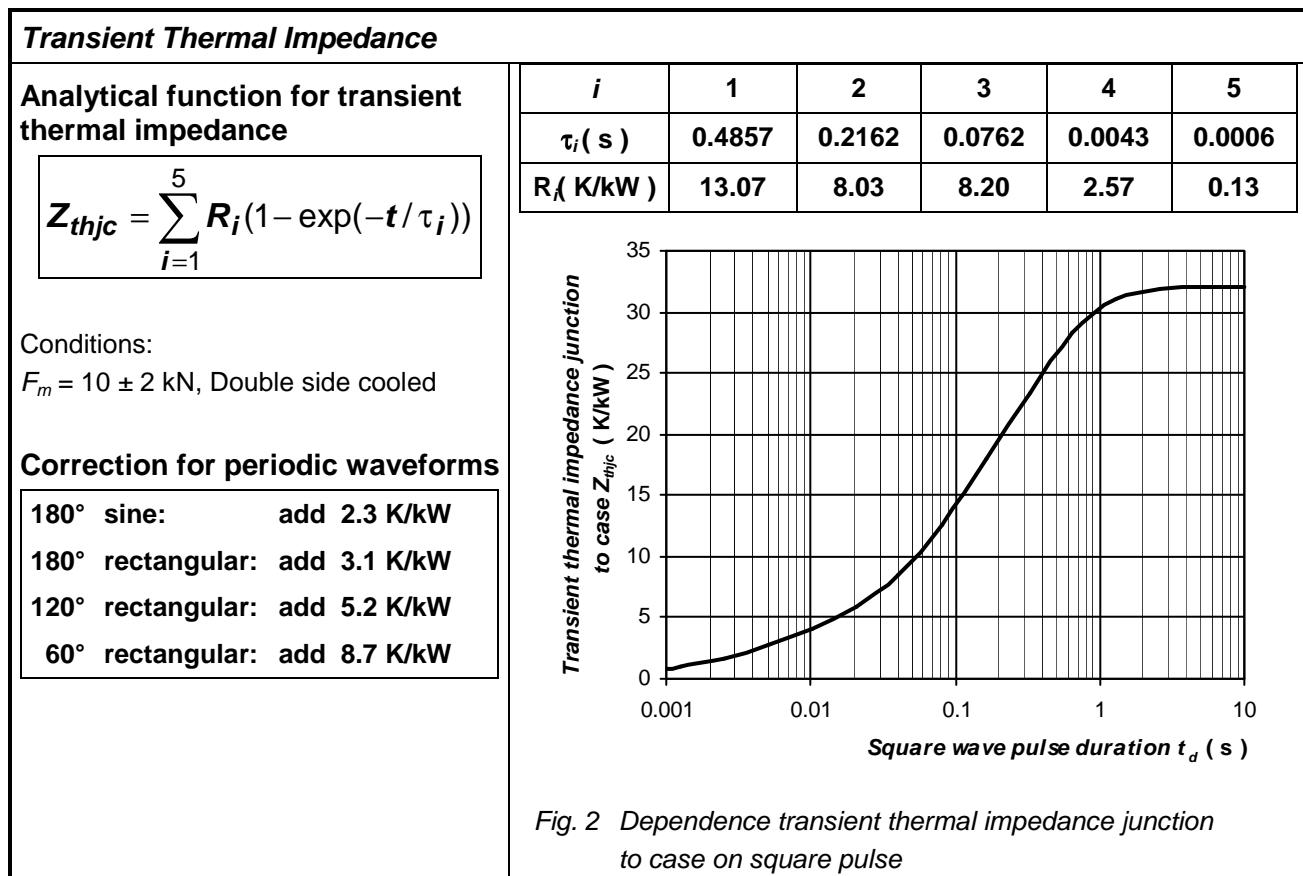
Unless otherwise specified  $T_j = 125^\circ\text{C}$

Note 1: De-rating factor of 0.13%  $V_{RRM}$  or  $V_{DRM}$  per  $^\circ\text{C}$  is applicable for  $T_j$  below 25  $^\circ\text{C}$

<b>Characteristics</b>		<b>Value</b>			<b>Unit</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>	
$V_{TM}$	<b>Maximum peak on-state voltage</b> $I_{TM} = 1\ 500\ A$			3.200	V
$V_{To}$ $r_T$	<b>Threshold voltage</b> <b>Slope resistance</b> $I_{T1} = 833\ A, I_{T2} = 2\ 498\ A$			2.551 0.430	V mΩ
$I_{DM}$	<b>Peak off-state current</b> $V_D = V_{DRM}$			70	mA
$I_{RM}$	<b>Peak reverse current</b> $V_R = V_{RRM}$			70	mA
$t_{gd}$	<b>Delay time</b> $T_j = 25\ ^\circ C, V_D = 0.4\ V_{DRM}, I_{TM} = I_{TAVm},$ $t_r = 0.3\ \mu s, I_{GT} = 2\ A$			2.0	μs
$t_{q1}$	<b>Turn-off time</b> $I_T = 500\ A, dI_T/dt = -50\ A/\mu s,$ $V_R = 100\ V, V_D = 2/3\ V_{DRM},$ $dv_D/dt = 50\ V/\mu s$	group of $t_q$ G H I		25.0 32.0 40.0	μs
$Q_{rr}$	<b>Recovery charge</b> <i>the same conditions as at <math>t_{q1}</math></i>			260	μC
$I_{rrM}$	<b>Reverse recovery current</b> <i>the same conditions as at <math>t_{q1}</math></i>			110	A
$I_H$	<b>Holding current</b>	$T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$		250 150	mA
$I_L$	<b>Latching current</b>	$T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$		1 500 1 000	mA
$V_{GT}$	<b>Gate trigger voltage</b> $V_D = 12V, I_T = 4\ A$	$T_j = -40\ ^\circ C$ $T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$	0.25	4 3 2	V
$I_{GT}$	<b>Gate trigger current</b> $V_D = 12V, I_T = 4\ A$	$T_j = -40\ ^\circ C$ $T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$	10	1000 500 300	mA

Unless otherwise specified  $T_j = 125\ ^\circ C$

<b>Thermal Parameters</b>		<b>Value</b>	<b>Unit</b>
$R_{thjc}$	<b>Thermal resistance junction to case</b> <i>double side cooling</i>	32.0	K/kW
	<i>anode side cooling</i>	52.0	
	<i>cathode side cooling</i>	83.0	
$R_{thch}$	<b>Thermal resistance case to heatsink</b> <i>double side cooling</i>	10.0	K/kW
	<i>single side cooling</i>	20.0	



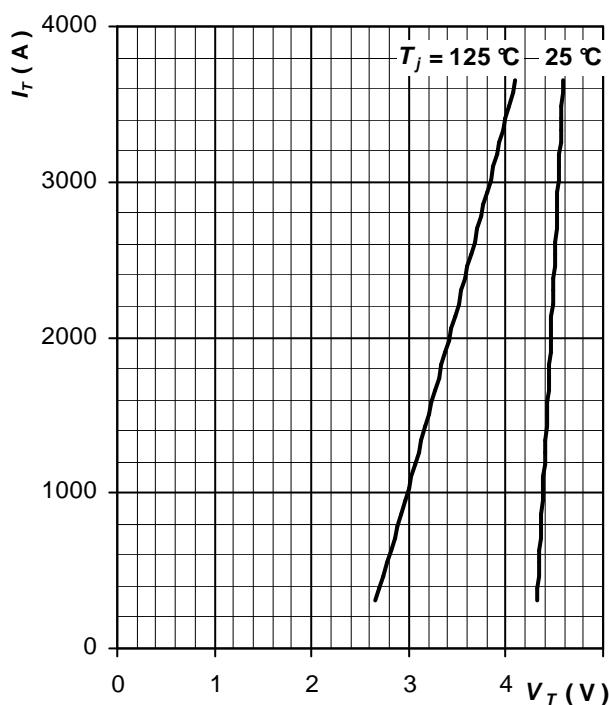
**On-State Characteristics**

Fig. 3 Maximum on-state characteristics

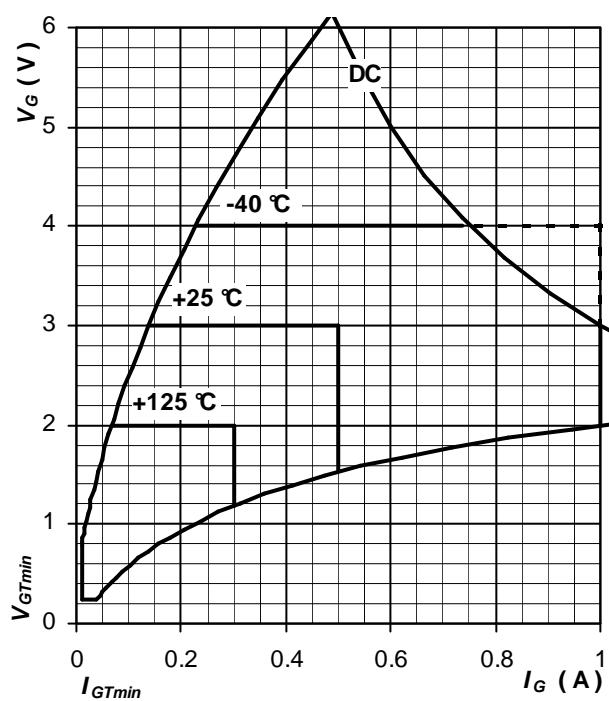
**Gate Trigger Characteristics**

Fig. 4 Gate trigger characteristics

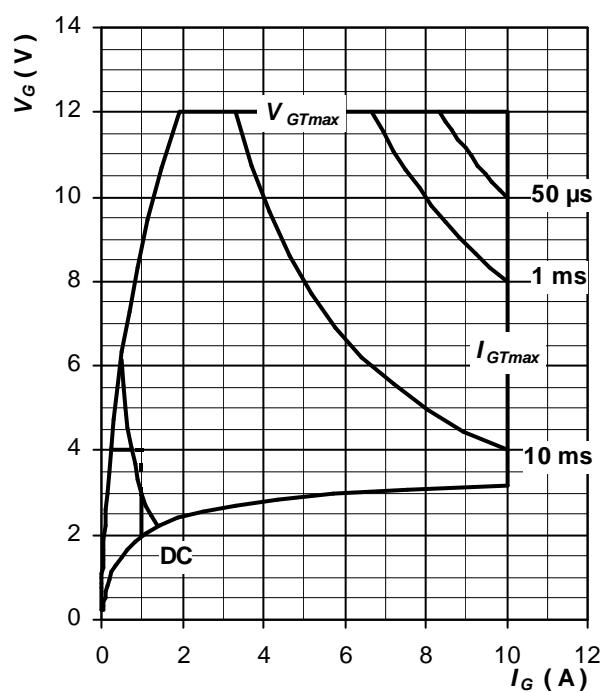


Fig. 5 Maximum peak gate power loss

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### Surge Characteristics

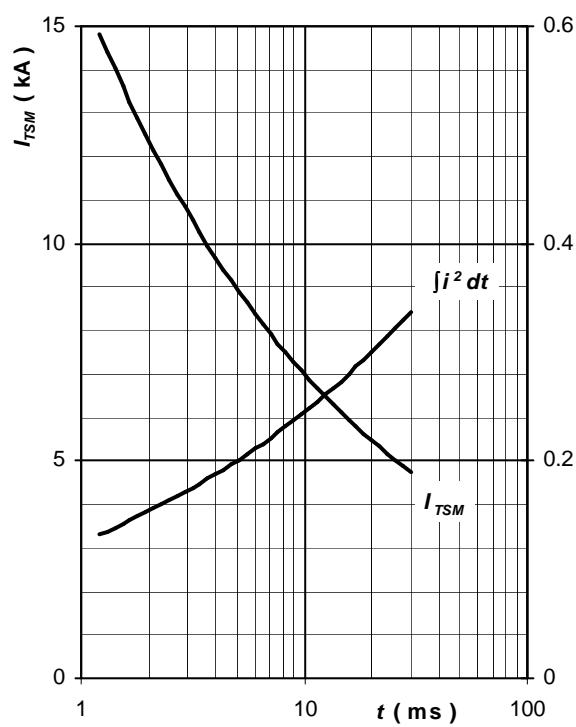


Fig. 6 Surge on-state current vs. pulse length,  
half sine wave, single pulse,  
 $V_R = 0 \text{ V}$ ,  $T_j = T_{jmax}$

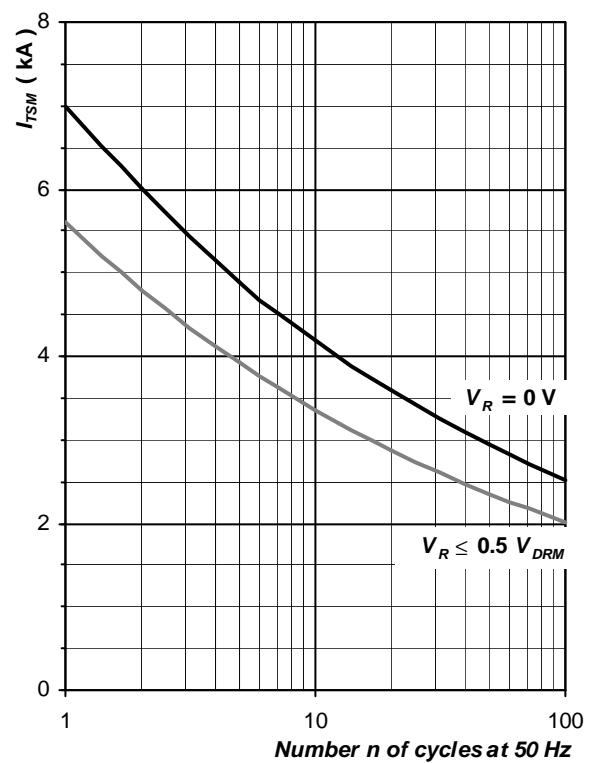


Fig. 7 Surge on-state current vs. number  
of pulses, half sine wave,  $T_j = T_{jmax}$

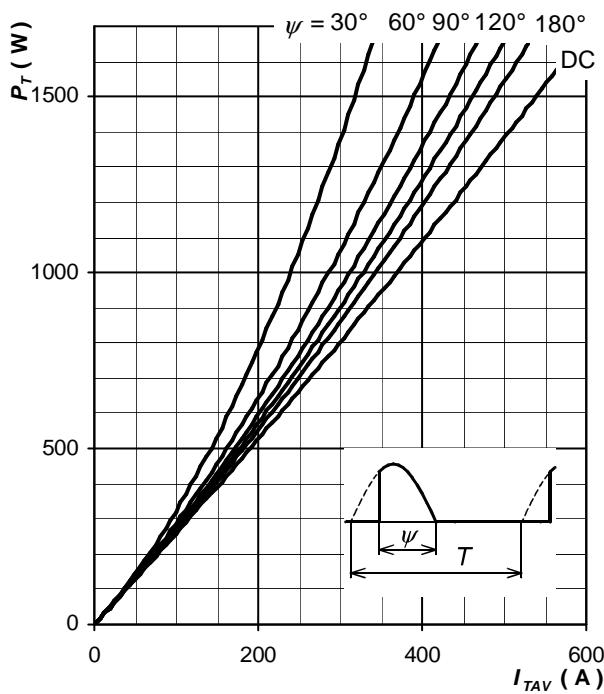
**Power Loss and Maximum Case Temperature Characteristics**


Fig. 8 On-state power loss vs. average on-state current, sine waveform,  $f = 50$  Hz,  $T = 1/f$

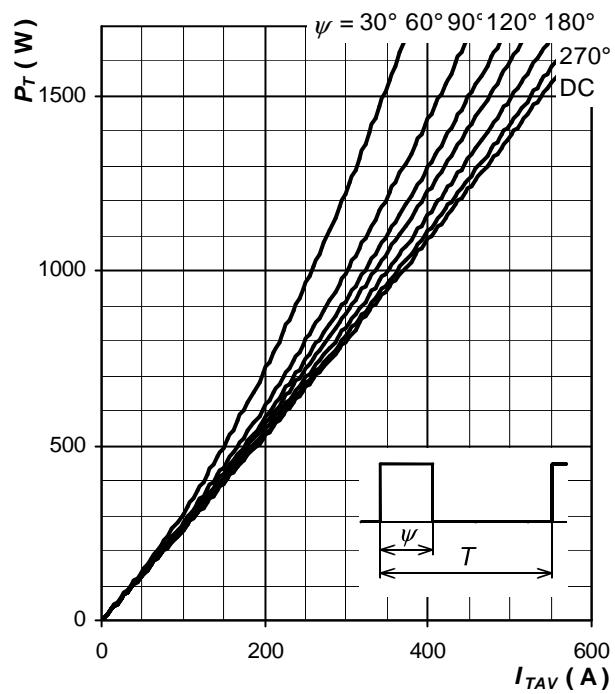


Fig. 9 On-state power loss vs. average on-state current, square waveform,  $f = 50$  Hz,  $T = 1/f$

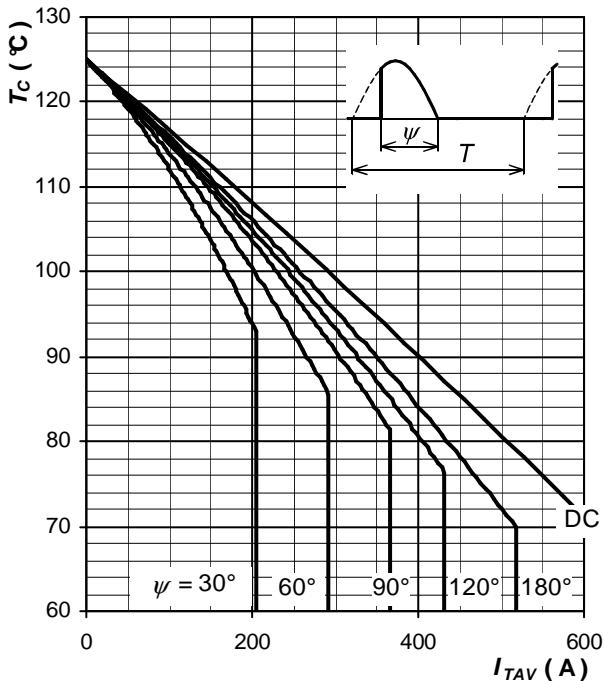


Fig. 10 Max. case temperature vs. aver. on-state current, sine waveform,  $f = 50$  Hz,  $T = 1/f$

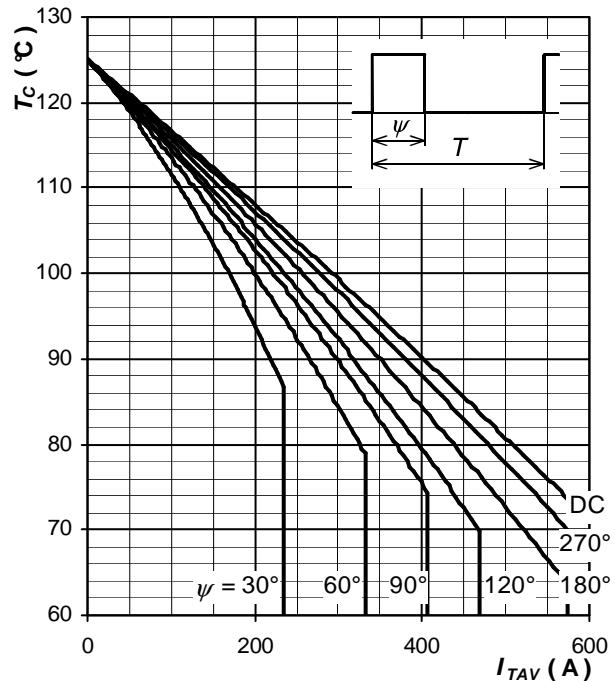


Fig. 11 Max. case temperature vs. aver. on-state current, square waveform,  $f = 50$  Hz,  $T = 1/f$

Note 2: Figures number 8 ÷ 11 have been calculated without considering any turn-on and turn-off losses. They are valid for  $f = 50$  or  $60$  Hz operation.

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### Turn-off Time, Parameter Relationship

Maximum values of turn-off time at application specific conditions are given by using this formula:

$$t_q = t_{q1} \cdot \frac{t_q}{t_{q1}}(T_j) \cdot \frac{t_q}{t_{q1}}(dv_D/dt) \cdot \frac{t_q}{t_{q1}}(-di_T/dt)$$

where:

$t_{q1}$  is turn-off time at standard conditions,  
see section "Characteristics"

$\frac{t_q}{t_{q1}}(T_j)$  is factor to be taken from fig. 12

$\frac{t_q}{t_{q1}}(dv_D/dt)$  is factor to be taken from fig. 13

$\frac{t_q}{t_{q1}}(-di_T/dt)$  is factor to be taken from fig. 14

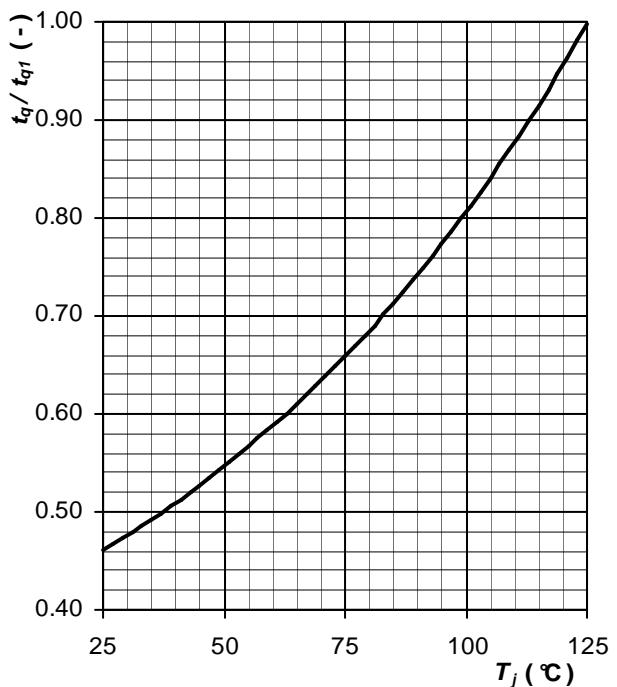


Fig. 12 Normalised maximum turn-off time  
vs. junction temperature

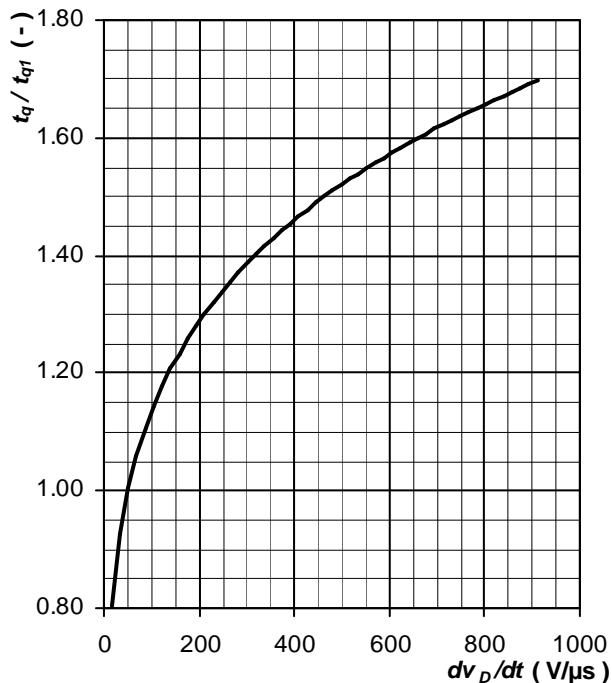


Fig. 13 Normalised maximum turn-off time  
vs. rate of rise of off-state voltage

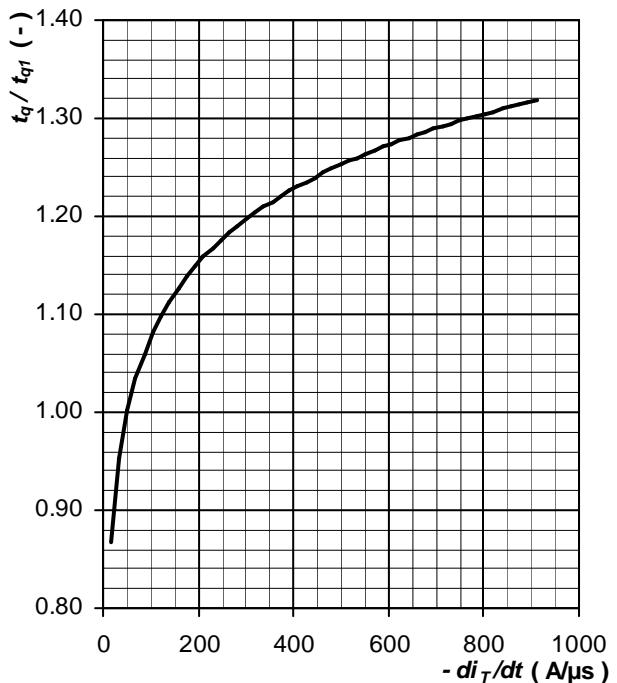


Fig. 14 Normalised maximum turn-off time  
vs. rate of fall of on-state current

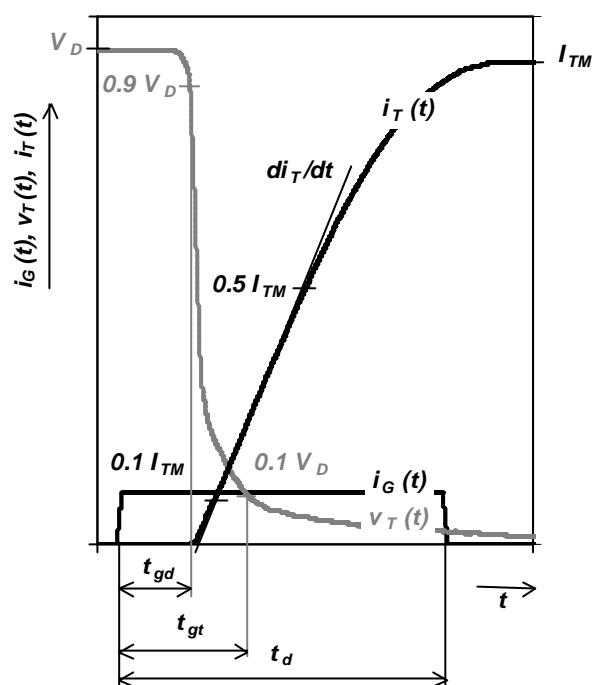
***Turn-on Characteristics***

Fig. 15 Typical waveforms and definition of symbols at turn-on of a thyristor

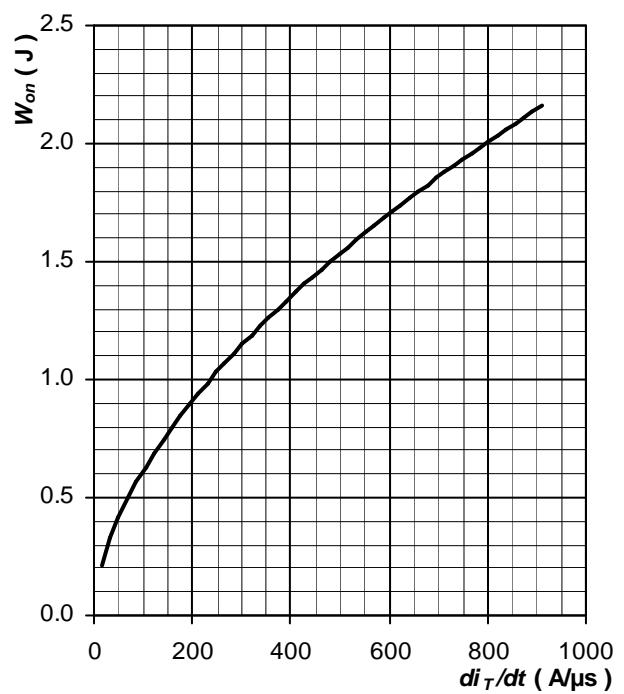


Fig. 16 Maximum turn-on energy per pulse vs. rate of rise on-state current,  $T_j = T_{jmax}$

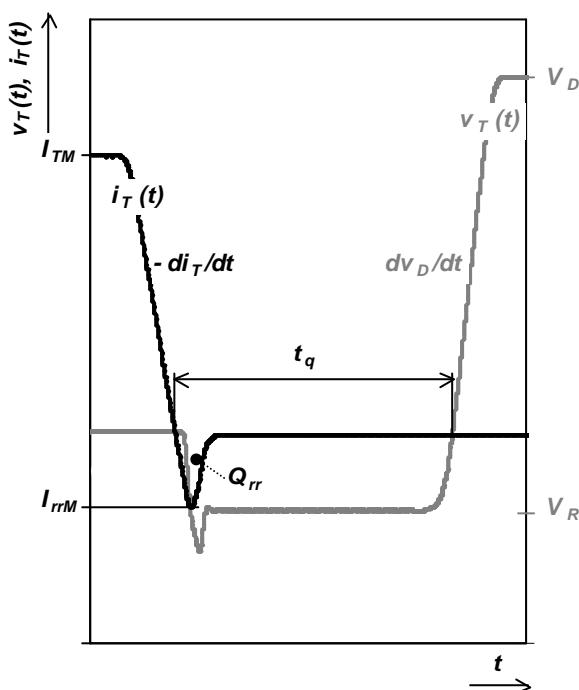
**Turn-off Characteristics**

Fig. 17 Typical waveforms and definition of symbols at turn-off of a thyristor, inductive switching without RC snubber

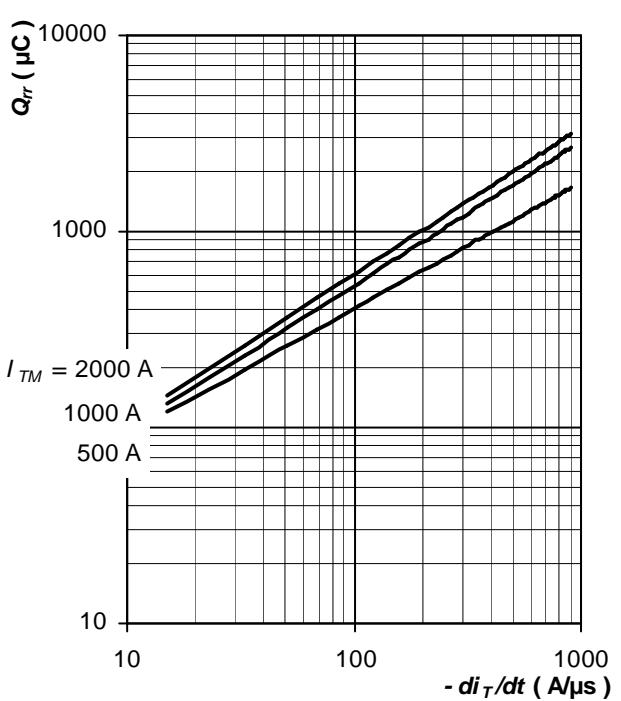


Fig. 18 Max. recovered charge vs. rate of fall on-state current, trapezoid pulse,  $V_R = 100 \text{ V}$ ,  $T_j = T_{j\max}$

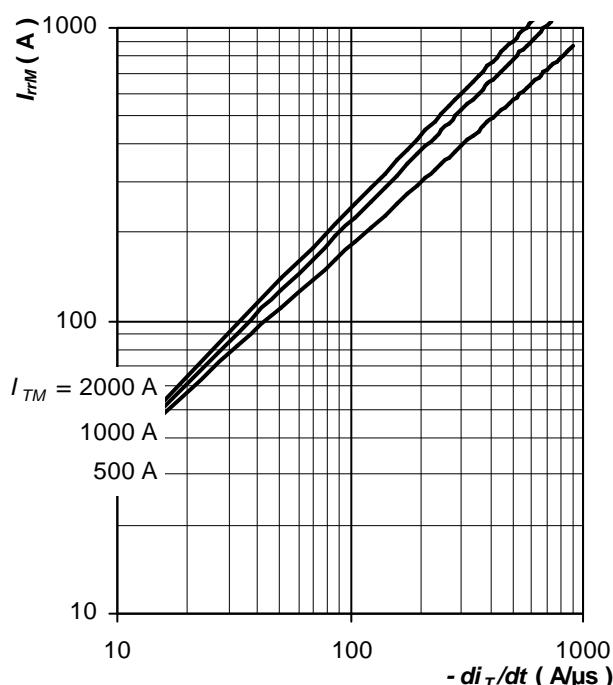


Fig. 19 Max. reverse recovery current vs. rate of fall on-state current, trapezoid pulse,  $V_R = 100 \text{ V}$ ,  $T_j = T_{j\max}$

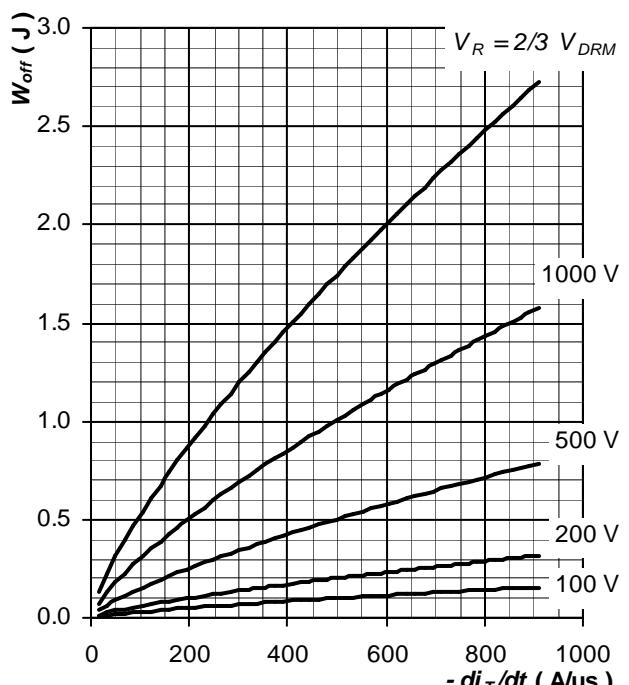


Fig. 20 Maximum turn-off energy per pulse vs. rate of fall on-state current, trapezoid pulse, inductive switching without RC snubber,  $I_{TM} = 2000 \text{ A}$ ,  $T_j = T_{j\max}$

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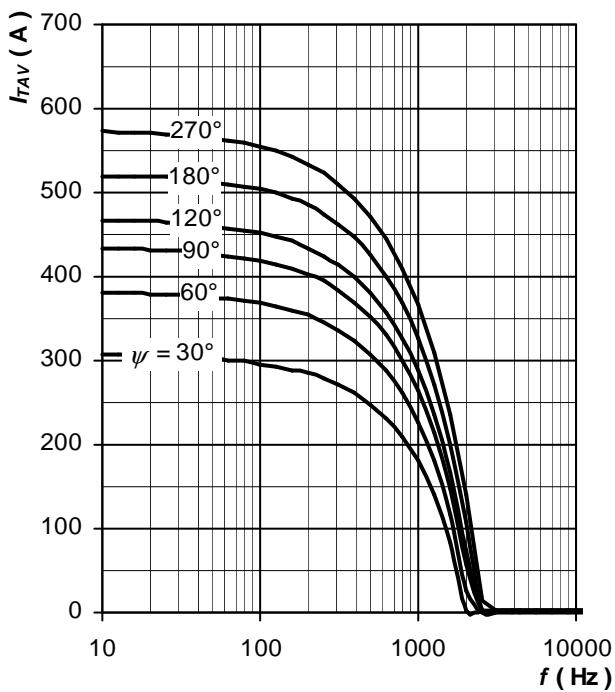
**Frequency Ratings**

Fig. 21 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$

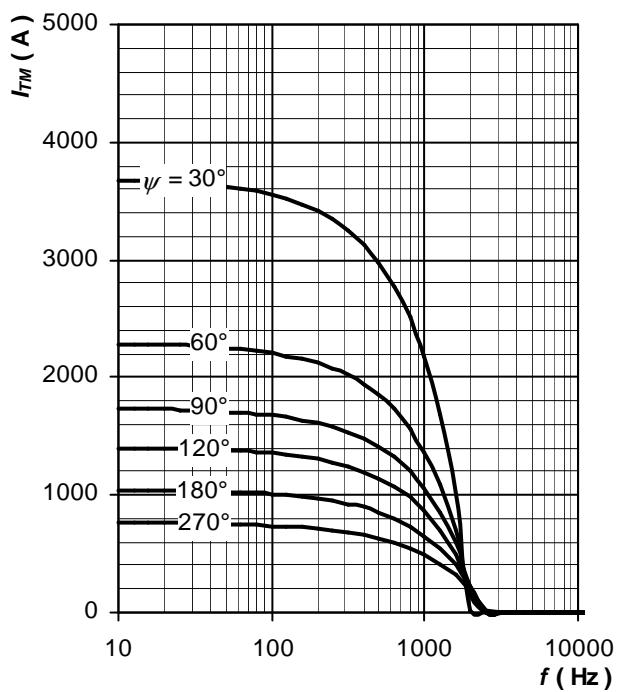


Fig. 22 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$

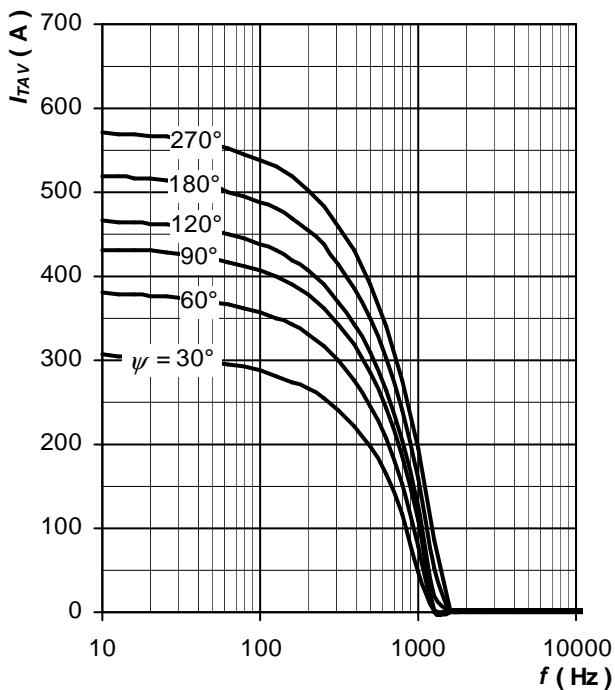


Fig. 23 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 V_{DRM}$

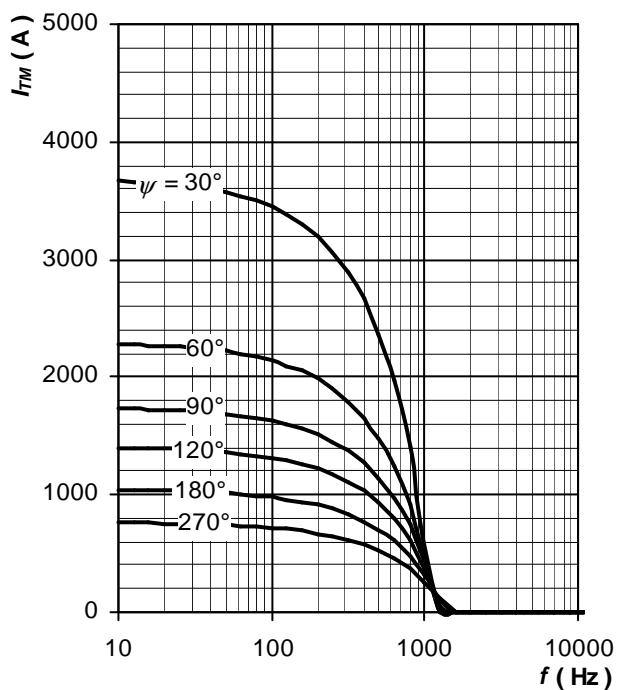
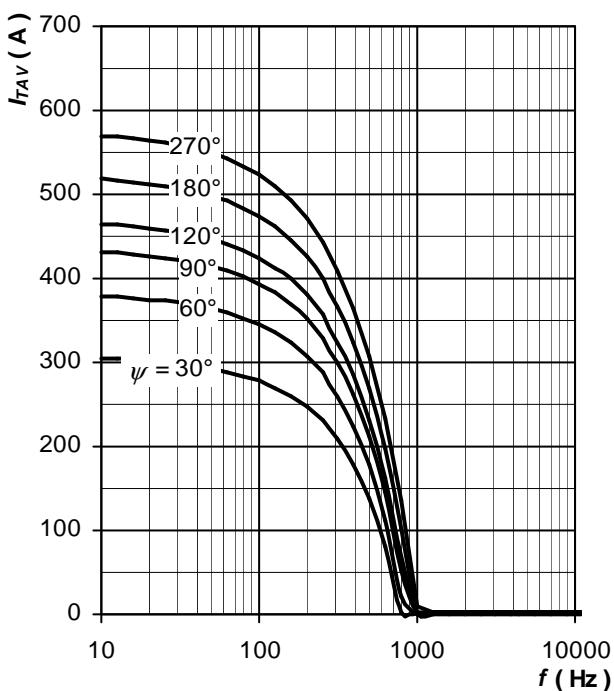
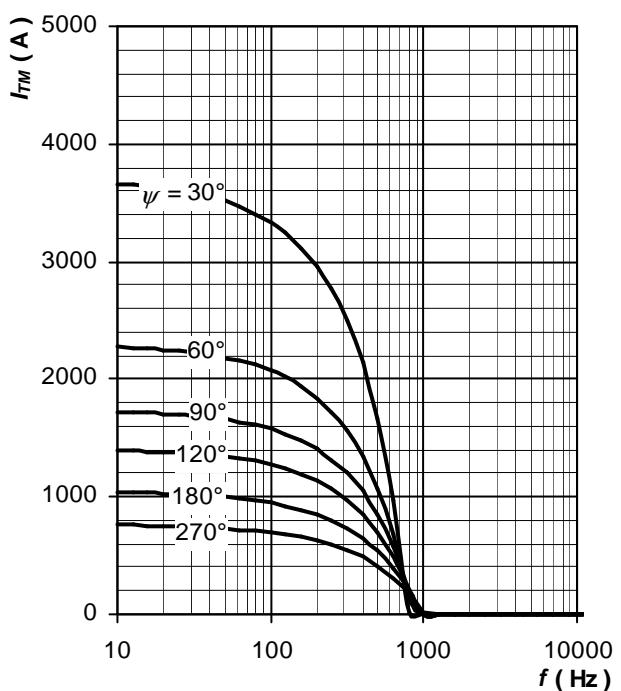


Fig. 24 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 V_{DRM}$

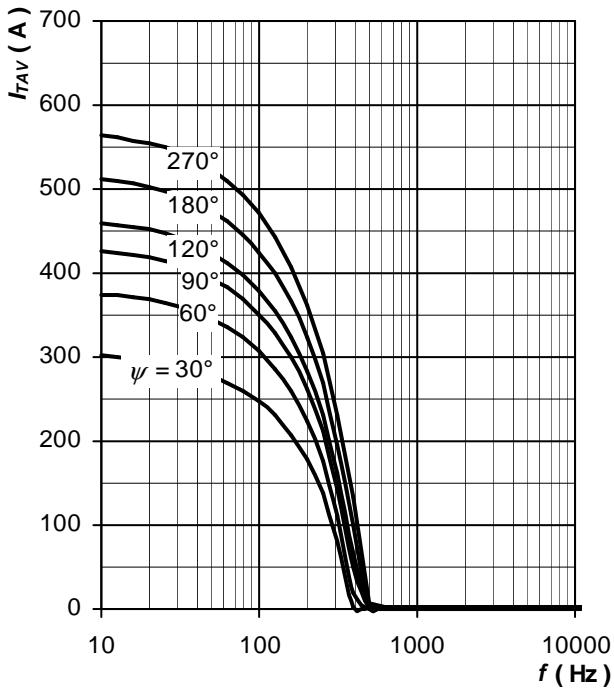
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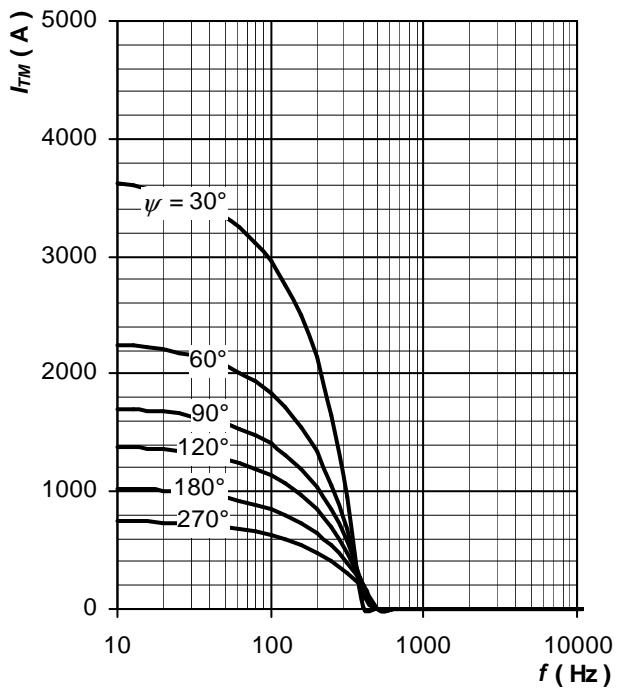
*Fig. 25 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$*



*Fig. 26 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$*

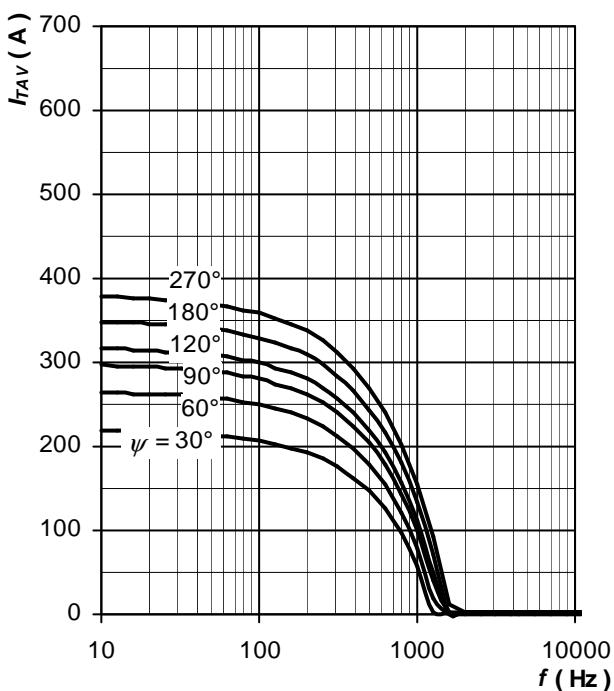


*Fig. 27 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 \text{ } V_{DRM}$*

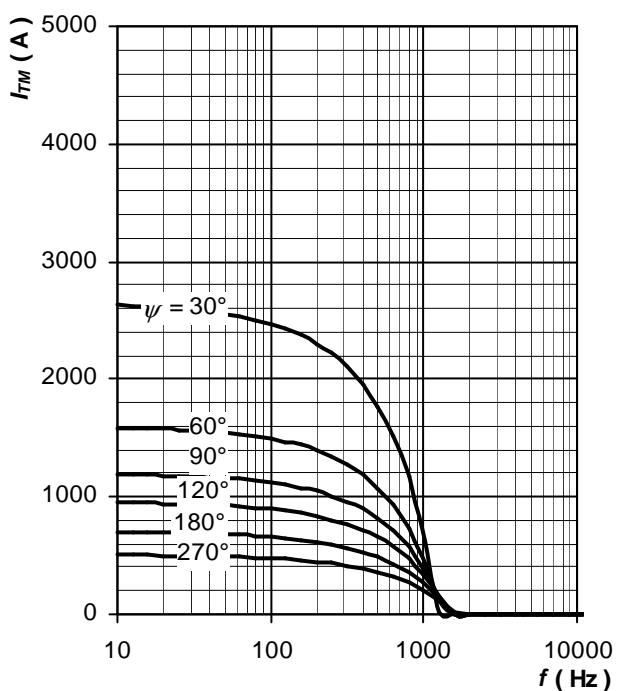


*Fig. 28 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 70 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 \text{ } V_{DRM}$*

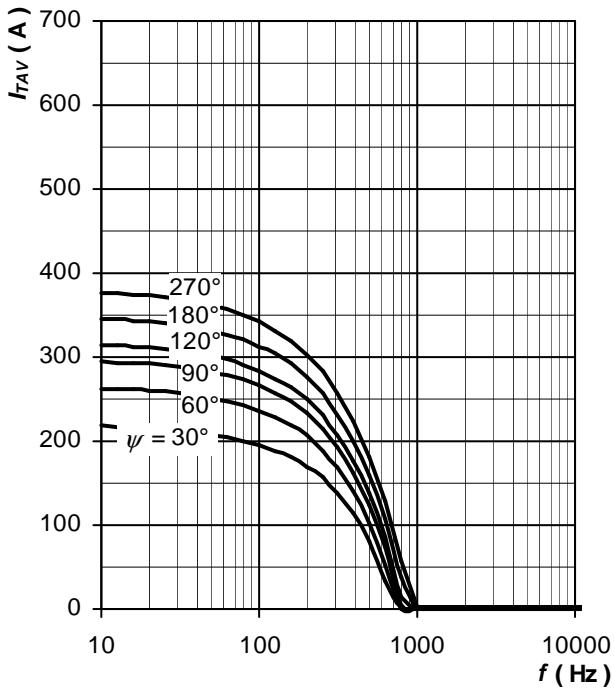
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**Frequency Ratings**

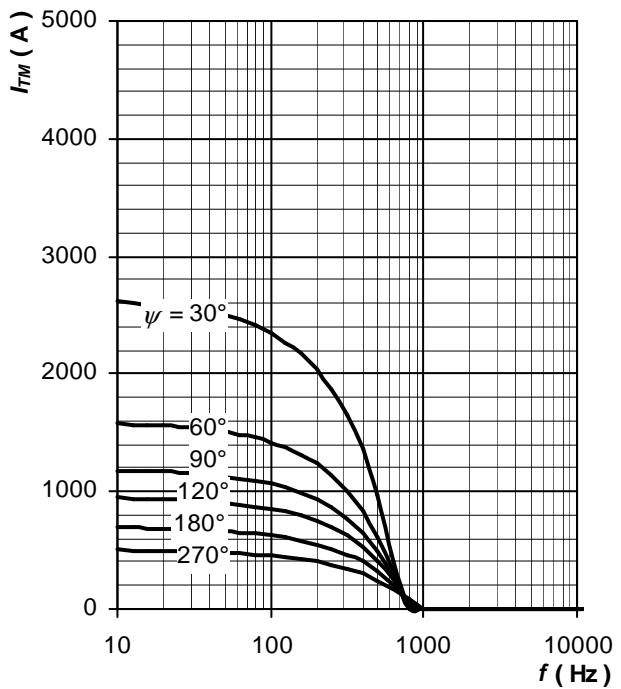
*Fig. 29 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$*



*Fig. 30 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$*



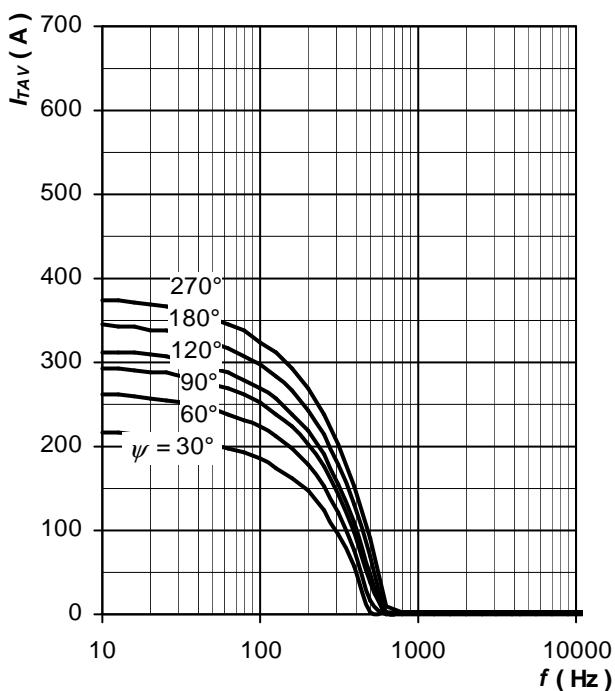
*Fig. 31 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 \text{ } V_{DRM}$*



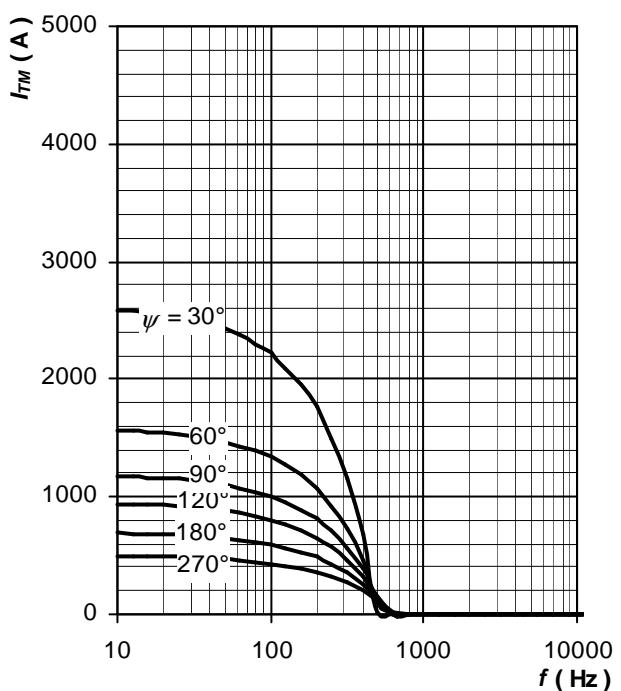
*Fig. 32 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 100 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 \text{ } V_{DRM}$*

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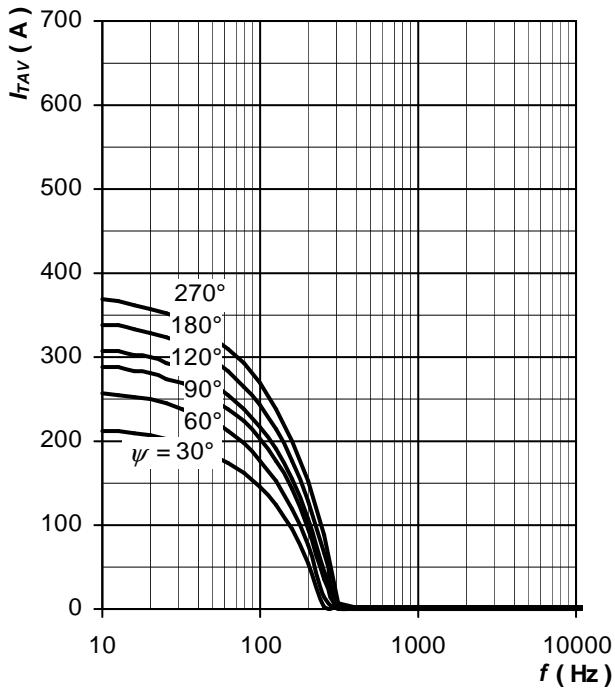
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**Frequency Ratings**

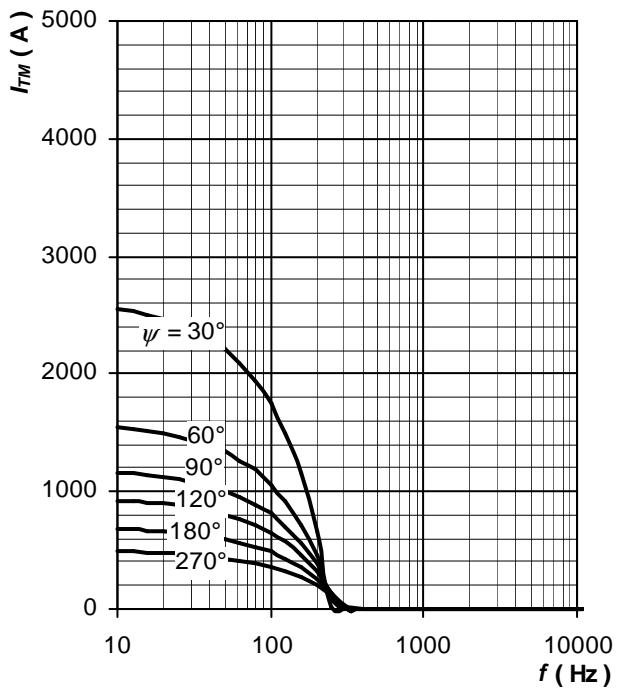
*Fig. 33 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$*



*Fig. 34 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 100 \text{ V}$*



*Fig. 35 Average on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 \text{ } V_{DRM}$*



*Fig. 36 Maximum on-state current vs. frequency,  
trapezoid waveform,  $T_C = 90 \text{ }^\circ\text{C}$ ,  
 $di_T/dt = \pm 500 \text{ A}/\mu\text{s}$ ,  $V_R = 2/3 \text{ } V_{DRM}$*

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Notes:

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